Ref #	Hits	Search Query	DBs ·	Default Operator	Plurals	Time Stamp
L1	139	coulomb adj blockade adj effect: resistance adj changing adj function	US-PGPUB; USPAT; EPO: JPO: DERWENT; IBM_TDB US-PGPUB; US-PG; JPO; EPO; JPO; DERWENT; IBM_TDB	OR.	ON ON	2005/11/22 17:07 2005/11/22 17:27
L3	2403519 121	@ad>:20030312* @riad>:20030312* @pt1d>:20030312*	US-PGPUB; USPAT; EPO; JPO; DERWENT, IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR OR	ON ON	2005/11/22 17:08 2005/11/22 17:10 2005/11/22 17:10
L5 L6	39 2	memory adj function adj body memory adj function adj body not 3 .	IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR OR	ON. ON	2005/11/22 17:25 2005/11/22 17:30
L7 L8	2	(*20040183647*).PN: resistance adj function\$5 adj body	IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR	OFF ON	2005/11/22 17:25 2005/11/22 17:31
L9 L10	12 10	memory with 1 not 3 resistance and 9	IBM_TDB US:PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; US-PAT; EPO; JPO; DERWENT;	OR OR	ON.	2005/11/22 17:31 2005/11/22 17:33
L11.	9 1 244595	electrode and 10	IBM_TDB US.PGPUB; US.PAT; EPO; JPO; DERWENT; IBM_TDB US.PGPUB; US.PGPUB; US.PGPUB;	OR.	ON	2005/11/22 17:43 2005/11/22 17:55
£17.	206 11	(silicon adj. oxide silicon adj. dioxide sio "sio.sub.2") with (silver ag) with (silver adj.oxide "ag.sub.2o") not.3 electrode with 17	DERWENT; IBM_TDB US-PGPUB; USPAT; EPO: JPO; DERWENT; IBM_TDB US-PGPUB; USPAT; EPO; JPO;	OR OR	ON ON	2005/11/22 18:04 2005/11/22 18:04
L24 L25	82 0	(silver ag) with (silver ad) oxide: "ag.sub.2o.") with resist\$ with electrode not (3:19) (silver ag) adj particle with (silver adj oxide "ag.sub.2o") with resist\$ with electrode not (3:19)	DERWENT; IBM_TDB US:PGPUB; US:PGPUB; US:PGPUB; DERWENT; IBM_TDB US:PGPUB; US:PGPUB;	OR	ON.	2005/11/22 18:06 2005/11/22 18:07
L26 L27	3 81	(silver ag) adj particle with (silver adj oxide "ag.sub.20") with electrode not (3.19): (silver ag) adj particle with (silver adj oxide "ag.sub.20") not (3.19)	EPO; JPO; DERWENT; IBM_TDB US-PGPUB; US-PAT; US-PO; JPO; DERWENT; IBM_TDB US-PGPUB; US-PGPUB;	OR	ON.	2005/11/22 18:08 2005/11/22 18:30 2005/11/22 18:30
			EPO; JPO; DERWENT; IBM_TDB			

L28	7	memory and 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/22 18:10
L29	7	electrode and 28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/22 18:10
L30	1708	257/508,529,537.cc/s.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/22 18:30
L31	0	30 and 27:	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/22 18:30
L32	3	((silver ag) adj particle silver adj oxide "ag.sub.2o") and 30 not (3 19)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/22 18:39
L33	1	(memory adj element and first adj electrode and second adj electrode and memory adj function adj. body and insulator and conductive adj particle and barrier and passage and electric adj charges and current and changes and voltage and storage adj state and discriminated and magnitude).cim.	US-PGPUB	OR	ON	2005/11/22 18:43